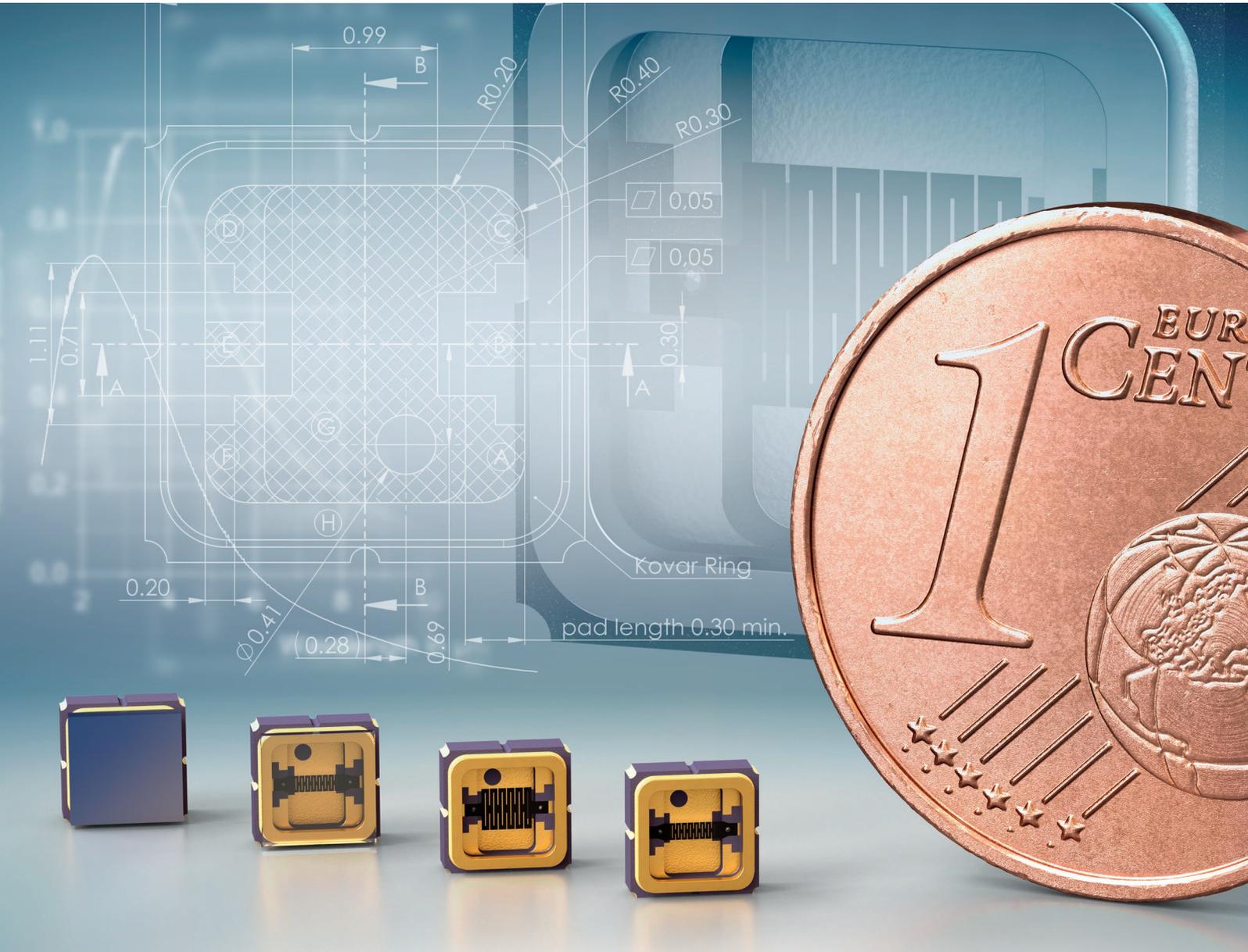


# INFRA·SOLID<sup>®</sup>



Data Sheet

## **HISsmd series**

Thermal Infrared Emitters

# HISsmd series

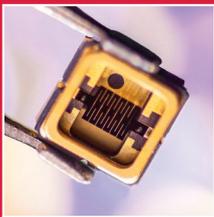
## Thermal Infrared Emitters

**HISsmd series** emitters are small, powerful infrared radiation sources that meet the demands for reliable miniaturized gas sensors and offer a wide range of new application scenarios. The low energy consumption, the high efficiency and the small size allow the use in portable, battery-powered, and mobile applications. These innovative infrared light sources are used, for instance, in respiratory gas analysis, e.g. for the detection of CO<sub>2</sub> and breath alcohol, and in Smart Home and Smartphone applications.

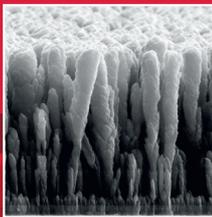
The pioneering SMD package enables a fully automated production in high-volume markets.

Infrasolid's infrared radiation sources are pulsable thermal emitters with a near black-body emittance. Based on a patented nanotechnology and a patented emitter set-up made of a high-melting metal, the free-standing monolithic radiating element and the nanostructured emitter surface offer numerous advantages in many applications.

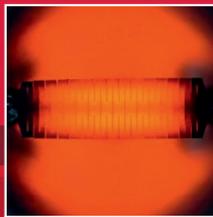
### Key features



**Very small size**



**High efficiency**



**High radiant power**

- ✓ Pulsable thermal black-body infrared source mounted in a SMD package with a size of 3 x 3 mm.
- ✓ Patented nanostructured radiating element achieves up to 500% more detection signal!
- ✓ Innovative surface technology for customized SMD products.
- ✓ Wide wavelength range enables applications in mobile, portable devices and various wearables, for miniaturized gas measurement sensors and hand-held spectrometers.

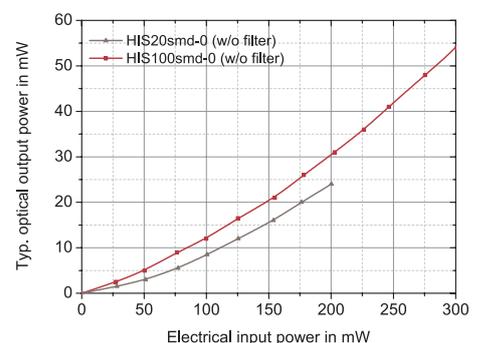
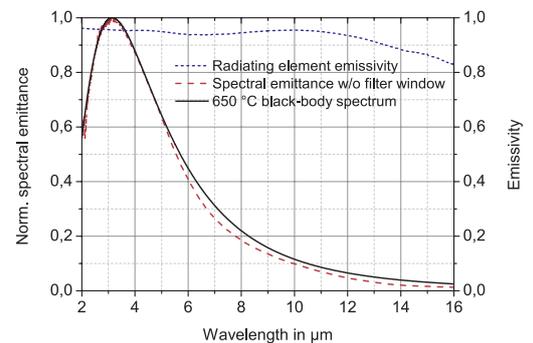
*innovative infrared sources for gas detection & spectroscopy*

### Main specifications

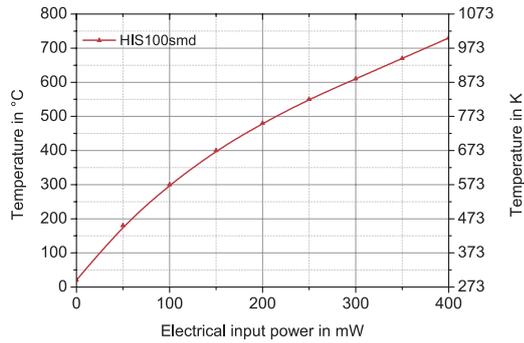
| Parameter                     | HIS20smd               | HIS100smd              |
|-------------------------------|------------------------|------------------------|
| Package                       | SMD3                   | SMD3                   |
| Radiating element area        | 0.24 mm <sup>2</sup>   | 1 mm <sup>2</sup>      |
| Radiating element emissivity  | > 0.9                  | > 0.9                  |
| Radiating element temperature | 700 °C at 175 mW       | 600 °C at 290 mW       |
| Optical output power**        | up to 20 mW            | up to 50 mW            |
| Max. electrical power (DC)    | 175 mW                 | 290 mW                 |
| Max. electrical voltage       | 1.05 V                 | 1.7 V                  |
| Max. electrical current       | 170 mA                 | 170 mA                 |
| Electrical resistance         | 5...6 Ω                | 9...10 Ω               |
| Modulation frequency*         | 10 Hz                  | 7 Hz                   |
| Filter (soldered window)      | Si-ARC, Sapphire, ZnSe | Si-ARC, Sapphire, ZnSe |
| Wavelength range**            | 2 to 16 μm             | 2 to 16 μm             |

\* 70 % modulation depth, square wave signal, 50 % duty cycle  
 \*\* depending on filter transmissivity

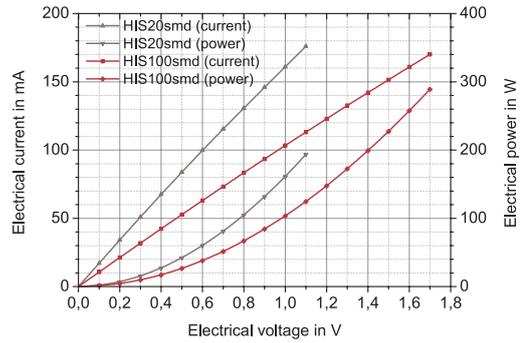
### Optical specifications



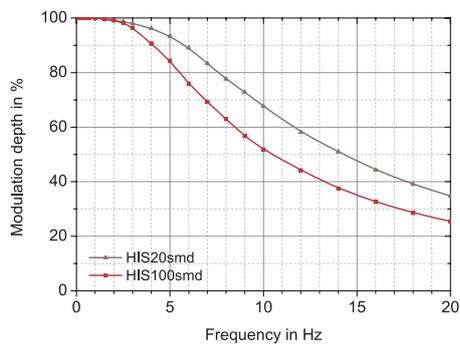
### Radiating element temperature



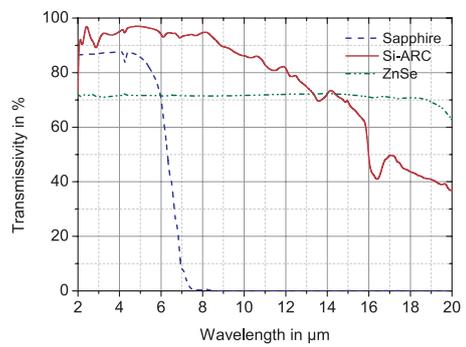
### Electrical specifications



### Modulation depth



### Window material transmissivity



| HIS20smd       | HIS100smd      | Window options         |
|----------------|----------------|------------------------|
|                |                |                        |
| Without window | Without window | Si-ARC, Sapphire, ZnSe |
|                |                |                        |

